FEATURES

• 150 °C T_J operation

High Performance Schottky Rectifier, 2 x 15 A

• Center tap D²PAK (TO-263AB) and TO-262AA packages

VS-MBRB25..CT-M3, VS-MBR25..CT-M3

- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance

Vishay Semiconductors

- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CI	HARACTERISTICS		
SYMBOL	CHARACTERISTICS	VALUES	UNITS
I _{F(AV)}	Rectangular waveform (per device)	30	٨
I _{FRM}	T _C = 130 °C (per leg)	30	A
V _{RRM}		35/45	V
I _{FSM}	t _p = 5 μs sine	1060	A
V _F	30 A _{pk} , T _J = 125 °C	0.73	V
Тј	Range	-65 to +150	°C

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-MBRB2535CT-M3 VS-MBR2535CT-1-M3	VS-MBRB2545CT-M3 VS-MBR2545CT-1-M3	UNITS
Maximum DC reverse voltage	V _R	35	45	V
Maximum working peak reverse voltage	V _{RWM}		45	v

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TO-262AA Base common cathode 02 ტ 2 10 Common C 3 Anode cathode Anode

VS-MBRB25..CT-M3

Anode

ტ 2

Common 🖒 3

cathode Anode

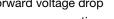
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VS-MBR25..CT-1-M3

PRIMARY CHARACTE	RISTICS
I _{F(AV)}	2 x 15 A
V _R	35 V, 45 V
V _F at I _F	See datasheet
I _{RM} max.	40 mA at 125 °C
T _J max.	150 °C
E _{AS}	16 mJ
Package	D ² PAK (TO-263AB), TO-262AA
Circuit configuration	Common cathode

RoHS COMPLIANT

HALOGEN FREE





ABSOLUTE MAXIMUM RATI	NGS				
PARAMETER	SYMBOL	TEST	CONDITIONS	VALUES	UNITS
Maximum average per leg		$T_{\rm C} = 130 ^{\circ}\text{C}$, rated $V_{\rm B}$		15	
forward current per device	F(AV)	$T_{\rm C} = 150$ C, rated $v_{\rm R}$		30	
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave	e, 20 kHz, T _C = 130 °C	30	
Non-repetitive peak surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1060	A
		Surge applied at rated single phase, 60 Hz	load conditions halfwave,	150	
Non-repetitive avalanche energy per leg	E _{AS}	$T_{J} = 25 \ ^{\circ}C, \ I_{AS} = 2 \ A, \ L$. = 8 mH	16	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linea Frequency limited by T	rly to zero in 1 μs J maximum V _A = 1.5 x V _R typical	2	А

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS			
Maximum forward valtage drep	V _{EM} ⁽¹⁾	30 A	T _J = 25 °C	0.82				
Maximum forward voltage drop	VFM ()	30 A	T _J = 125 °C	0.73	V			
Maximum instantaneous	I _{BM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.2	mA			
reverse current	IRM \''	T _J = 125 °C	naleu DC vollage	40	ШA			
Threshold voltage	V _{F(TO)}			0.355	V			
Forward slope resistance	r _t	$T_J = T_J$ maximum		12.3	mΩ			
Maximum junction capacitance	CT	V _R = 5 V _{DC} (test signal rang	ge 100 kHz to 1 MHz), 25 °C	700	pF			
Typical series inductance	Ls	Measured from top of term	Measured from top of terminal to mounting plane					
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs			

Note

 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHA	NICAL SP	PECIFICA	TIONS		
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperat	ure range	ТJ		-65 to 150	0°
Maximum storage temperature range		T _{Stg}		-65 to 175	0
Maximum thermal resistance junction to case per leg),	R _{thJC}	DC operation	1.5	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	0/10
Approximate weight				2	g
Approximate weight				0.07	oz.
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf · cm
Mounting torque	maximum		Non-Indificated threads	12 (10)	(lbf ⋅ in)
Marilian davian			Case style D ² PAK (TO-263AB)	MBRB2 MBRB2	2535CT 2545CT
Marking device			Case style TO-262AA	MBR25 MBR25	



VS-MBRB25..CT-M3, VS-MBR25..CT-M3

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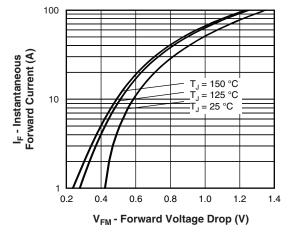


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

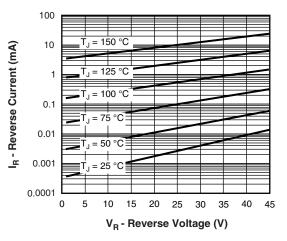


Fig. 2 - Typical Values of Reverse Current vs.Reverse Voltage (Per Leg)

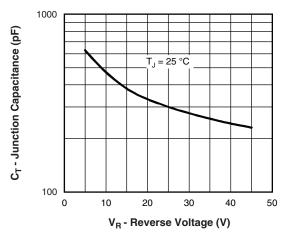


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

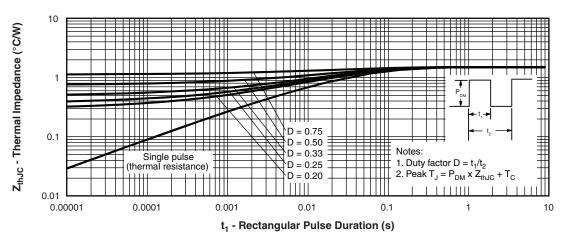
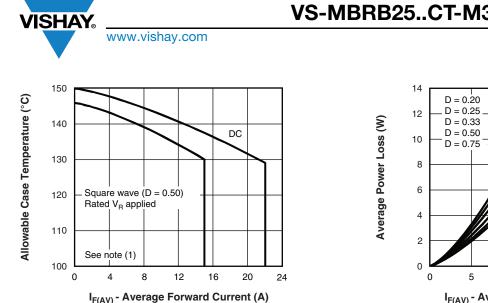
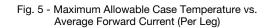


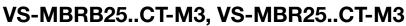
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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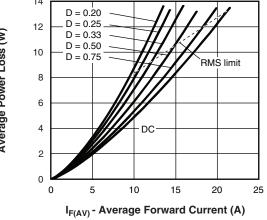


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

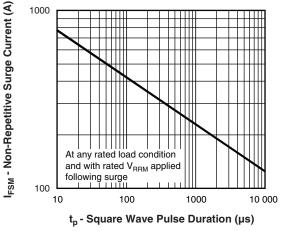


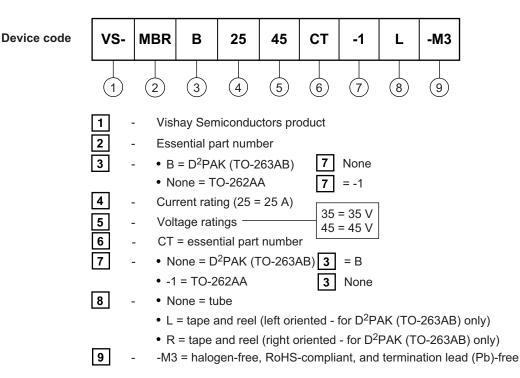
Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

 $^{(1)} \mbox{ Formula used: } T_C = T_J - (Pd + Pd_{REV}) \ x \ R_{thJC}; \\ Pd = \mbox{ forward power loss = } I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ fig. \ 6); \\ Pd_{REV} = \mbox{ inverse power loss = } V_{R1} \ x \ I_R \ (1 - D); \ I_R \ at \ V_{R1} = \ rated \ V_R$



ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)				
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION		
VS-MBRB2535CTL-M3	800	13" diameter plastic tape and reel		
VS-MBRB2535CT-M3	50	Antistatic plastic tubes		
VS-MBRB2535CTR-M3	800	13" diameter plastic tape and reel		
VS-MBRB2545CTL-M3	800	13" diameter plastic tape and reel		
VS-MBRB2545CT-M3	50	Antistatic plastic tubes		
VS-MBRB2545CTR-M3	800	13" diameter plastic tape and reel		
VS-MBR2535CT-1-M3	50	Antistatic plastic tubes		
VS-MBR2545CT-1-M3	50	Antistatic plastic tubes		

	LINKS TO RELATE	ED DOCUMENTS
Dimensions -	D ² PAK (TO-263AB)	www.vishay.com/doc?96164
Dimensions	TO-262AA	www.vishay.com/doc?96165
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444
Part marking information –	TO-262AA	www.vishay.com/doc?95443
Packaging information		www.vishay.com/doc?96424

D²PAK

DIMENSIONS in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STNDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	2.54 BSC		0.100 BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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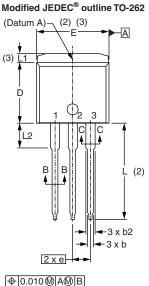
Outline Dimensions

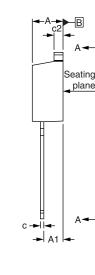


Vishay Semiconductors

TO-262AA

DIMENSIONS in millimeters and inches





F D1 (3) (3) Section A - A Base (4) Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None





Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

SYMBOL	MILLIN	IETERS	INC	HES	NOTEO
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.51 0.89		0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

 ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
 ⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the second dimensioner of the second dimensis of the second dimensioner of the second dimensioner of the the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only (5)

Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

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